IN THE CLAIMS

Please replace the current claims with the following complete set of claims, showing the amendments made thereto:

1. (Currently Amended) A circuit for limiting the in-rush current of a radio device coupled to a low-power external power source, comprising:

a switch circuit in series between said power source and said radio device, said switch having an "off" state with a <u>first</u> [high] impedance and an "on" state with a <u>second</u> [low] impedance <u>lower than said first impedance</u>; and

a time-delay shorting circuit coupled to said switch circuit, said time-delay shorting circuit having a time constant;

wherein before said time constant has elapsed, said switch circuit is in said <u>first</u> [high] impedance "off" state for limiting said in-rush current to said radio device and wherein after said time constant has elapsed, said switch circuit is in said <u>second</u> [low] impedance "on" state so that said radio device is powered by said external power source; and

wherein said switch circuit includes a field effect transistor having an "on" state resistance and being in parallel with an in-rush current limiting resistor having a resistance in the range of 5 to 10 ohms, wherein said resistance of said in-rush current limiting resistor is substantially said first impedance of said switch circuit and said field effect transistor on state resistance is substantially said second impedance of said switch circuit.

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- 3. (Currently Amended) The circuit of claim 1 [2], wherein said "on" state resistance of said field effect transistor is in the range of 0.05 to 0.2 ohms.
- 4. The circuit of claim 3, wherein said "on" state resistance of said field effect transistor is approximately 0.1 ohms.
- 5. CANCEL.
- 6. (Currently Amended) The circuit of claim 1 [5], wherein said resistance of said in-rush current limiting resistor is approximately 5 ohms.
- 7. (Currently Amended) The circuit of claim 1 [2], wherein said "on" state resistance of said field effect transistor is approximately 0.1 ohms and said resistance of said in-rush current limiting resistor is approximately 5 ohms.
- 8. The circuit of claim 1, wherein said time constant is in the range of 2 to 3 milliseconds.
- 9. (Currently Amended) The circuit of claim 1 [2], wherein said time-delay circuit includes a capacitor and a resistor, said capacitor having a first end coupled to said external power supply and a second end coupled to said field effect transistor and wherein said capacitor has a capacitance and said resistor has a resistance so that said time constant is in the range of 2 to 3 milliseconds.
- 10. The circuit of claim 1, wherein said radio device is provided in a compact flash form factor and said low-power external power source is provided in a handheld computing device and wherein said radio device is coupled to said handheld computing device.
- 11. (Currently Amended) The circuit of claim 1, wherein said circuit <u>for limiting</u> is in said radio device.

- 12. (Currently Amended) The circuit of claim 1, wherein said circuit <u>for limiting</u> is in said power source.
- 13. (Currently Amended) A method for limiting the in-rush current of a radio device coupled to a low-power external power source, comprising steps of:

inserting a switch circuit in series between said power source and said radio device, said switch having an "off" state with a <u>first</u> [high] impedance and an "on" state with a second [low] impedance lower than said first impedance; and

coupling a time-delay shorting circuit to said switch circuit, said time-delay shorting circuit having a time constant;

switching to said <u>first</u> [high] impedance "off" state for limiting said in-rush current to said radio device before said time constant has elapsed; and

switching to said <u>second</u> [low] impedance "on" state after said time constant has elapsed so that said radio device is powered by said external power source;

wherein said switch circuit includes a field effect transistor having an "on" state resistance in the range of 0.05 to 0.2 ohms, said field effect transistor being in parallel with a in-rush current limiting resistor having a resistance in the range of 5 to 10 ohms, wherein said resistance of said in-rush current limiting resistor is substantially said first impedance and said "on" state resistance of said field effect transistor is substantially said first impedance.

- 14. CANCEL.
- 15. (Currently Amended) The method of claim 13 [14], wherein said "on" state resistance of said field effect transistor is approximately 0.1 ohms and said resistance of said in-rush current limiting resistor is approximately 5 ohms.

- 16. The method of claim 13, wherein said time constant is in the range of 2 to 3 milliseconds.
- 17. (Currently Amended) The method of claim 13 [14], wherein said time-delay circuit includes a capacitor and a resistor, said capacitor having a first end coupled to said external power supply and a second end coupled to said field effect transistor and wherein said capacitor has a capacitance and said resistor has a resistance so that said time constant is in the range of 2 to 3 milliseconds.
- 18. The method of claim 13, wherein said radio device is provided in a compact flash form factor and said low-power external power source is provided in a handheld computing device and wherein said radio device is coupled to said handheld computing device.
- 19. The method of claim 13, further comprising the step of" placing said switch circuit and said time-delay shorting circuit in said radio device.
- 20. The method of claim 13, further comprising the step of"
 placing said switch circuit and said time-delay shorting circuit in said power supply.
- 21. (Currently Amended) A radio device provided in a compact flash form factor, said radio device being powered by a low-power external power source, comprising: radio electronics having an in-rush current demand;

a switch circuit in series between said power source and said radio device, said switch circuit having an "off" state with a <u>first</u> [high] impedance and an "on" state with a <u>second</u> [low] impedance <u>lower than the first impedance</u>; and

a time-delay shorting circuit coupled to said switch circuit, said time-delay shorting circuit having a time constant;

wherein before said time constant has elapsed, said switch circuit is in said <u>first</u>
[high] impedance "off" state for limiting said in-rush current to said radio device and wherein after said time constant has elapsed, said switch circuit is in said <u>second</u> [low] impedance "on" state so that said radio device is powered by said external power source; and

wherein said switch circuit includes a field effect transistor having an "on" state resistance in the range of 0.05 to 0.2 ohms, said field effect transistor being in parallel with a in-rush current limiting resistor having a resistance in the range of 5 to 10 ohms, wherein said high impedance is substantially said resistance of said in-rush current limiting resistor and said low impedance is substantially said "on" state resistance of said field effect transistor.

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- 23. (Currently Amended) The radio device of claim <u>21</u> [22], wherein said "on" state resistance of said field effect transistor is approximately 0.1 ohms and said resistance of said resistor is approximately 5 ohms.
- 24. (Currently Amended) The radio device of claim 21 [22], wherein said time-delay circuit includes a capacitor and a resistor, said capacitor having a first end coupled to said external power supply and a second end coupled to said field effect transistor and wherein said capacitor has a capacitance and said resistor has a resistance so that said time constant is in the range of 2 to 3 milliseconds.
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